NSN 5962-01-373-0566

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View Online at https://aerobasegroup.com/nsn/5962-01-373-0566

| Body Length: |
|---|
| 1.490 inches |
| Body Width: |
| Between 0.500 inches and 0.610 inches |
| Body Height: |
| 0.217 inches |
| Maximum Power Dissipation Rating: |
| 1.0 watts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Electrostatic sensitive and high impedance and w/disable and w/enable and ultraviolet erasable and programmed and w/buffered output |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Dual-in-line |
| Output Logic Form: |
| Transistor-transistor logic |
| Input Circuit Pattern: |
| 17 input |
| Case Outline Source And Designator: |
| D-10 mil-m-38510 |
| Current Rating Per Characteristic: |
| 125.00 milliamperes reverse current, dc absolute |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| -0.6 volts power source and 6.25 volts power source |
| Capitance Rating Per Characteristic: |
| 6.00 input picofarads and 12.00 output picofarads |
| Time Rating Per Chacteristic: |
| 250.00 nanoseconds access |
| Memory Device Type: |
| Eprom |
| Test Data Document: |
| 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). |
| Terminal Type And Quantity: |
| 28 printed circuit |

N/a

Shelf Life:

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| In | 18 | <i>(</i>)+ | МЛО | 201 | ure: |
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Demilitarization:

Yes - demil/mli

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